

SCD45



Power Rectifier Diodes

Applications

- Power Supplies
- Uncontrolled Rectifiers
- Battery Chargers

Features

- Full blocking capability over wide temperature range
- Hermetic metal case with glass insulator
- Threaded Stud

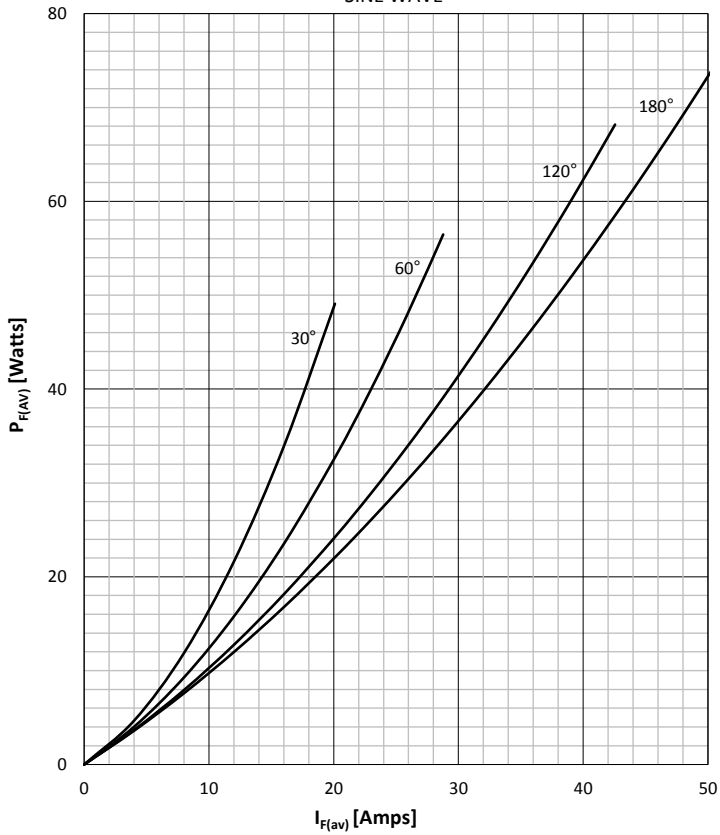
Key Parameters

V_{RRM}	= 1600V
$I_{F(AV)}$	= 50A
I_{FSM}	= 700A
$V_{F(TO)}$	= 0.85V
r_F	= 5.0mΩ

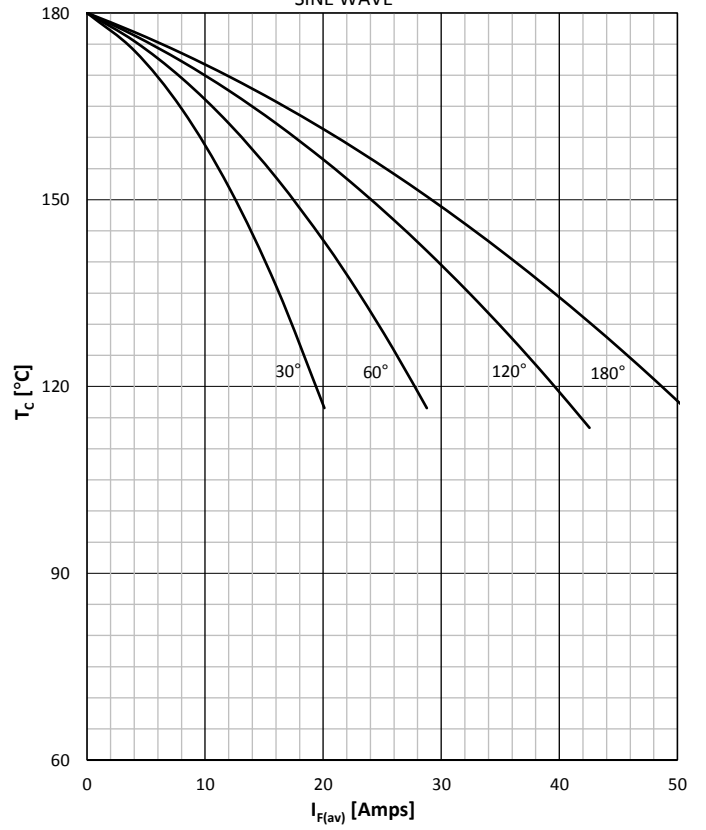
Symbol	Characteristic	Conditions	T_j [°C]	Value	Unit
BLOCKING					
V_{RRM}	Repetitive peak reverse voltage		180	200 - 1600	V
V_{RSM}	Non-repetitive peak reverse voltage		180	300 - 1700	V
I_{RRM}	Repetitive peak reverse current	$V = V_{RRM}$	180	5	mA
CONDUCTING					
$I_{F(AV)}$	Mean forward current	$180^\circ \sin, 50 \text{ Hz}, T_c=115^\circ\text{C}$ $T_c=125^\circ\text{C}$		50 45	A
I_{FRMS}	RMS current			80	A
I_{FSM}	Surge forward current	Sine wave, 10 ms Without reverse voltage	25	700	A
			180	600	A
$I^2 t$	$I^2 t$	Sine wave, 10 ms Without reverse voltage	25	2450	A ² s
			180	1800	A ² s
V_F	Forward voltage	On-state current = 150A	180	1.60	V
$V_{F(TO)}$	Threshold voltage		180	0.85	V
r_F	Forward slope resistance		180	5.0	mΩ
MOUNTING					
$R_{th(j-c)}$	Thermal impedance, sin 180°	Junction to case		0.85	°C/W
$R_{th(c-h)}$	Thermal impedance	Case to heatsink		0.25	°C/W
T_j	Max. junction temperature			180	°C
T_{stg}	Storage temperature			-40 180	°C
M	Mounting torque			4	NM
W	Weight (Approx.)			40	gm

DISSIPATION CHARACTERISTICS

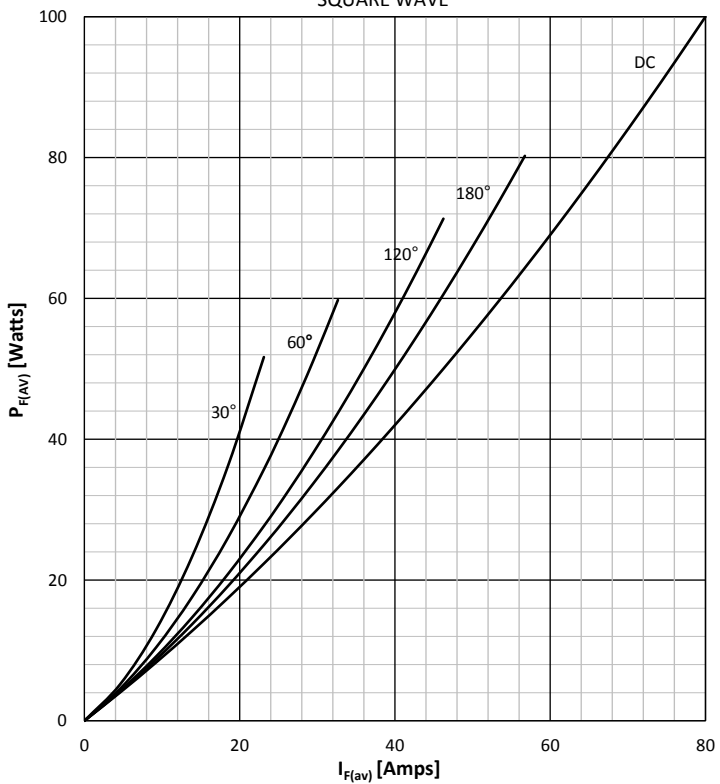
SINE WAVE


FORWARD CURRENT DERATING CURVE

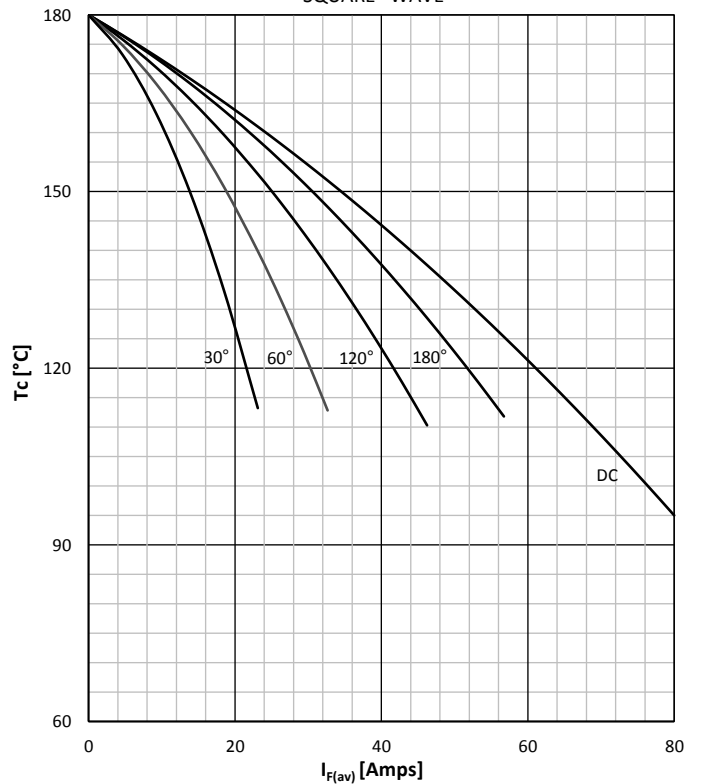
SINE WAVE

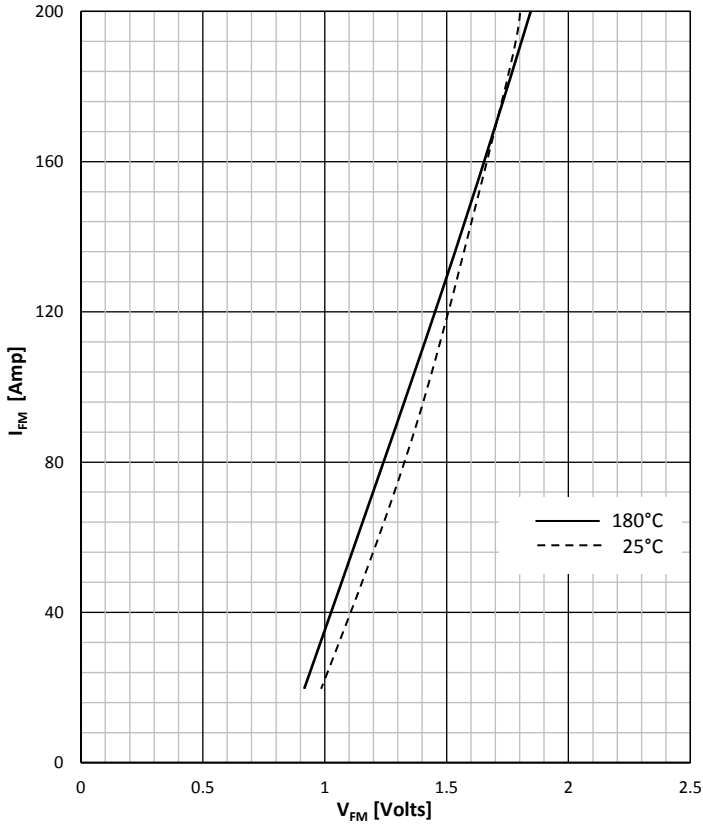
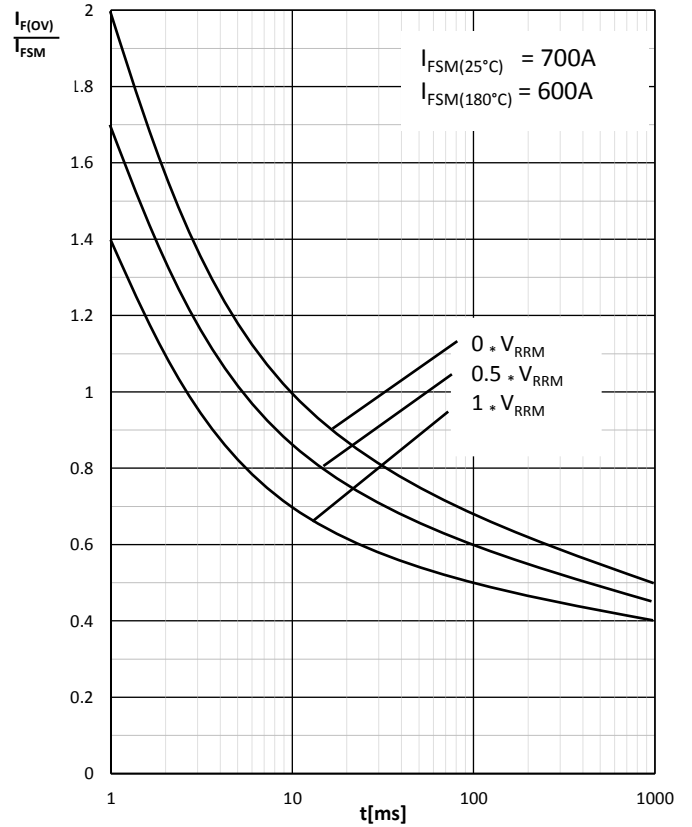
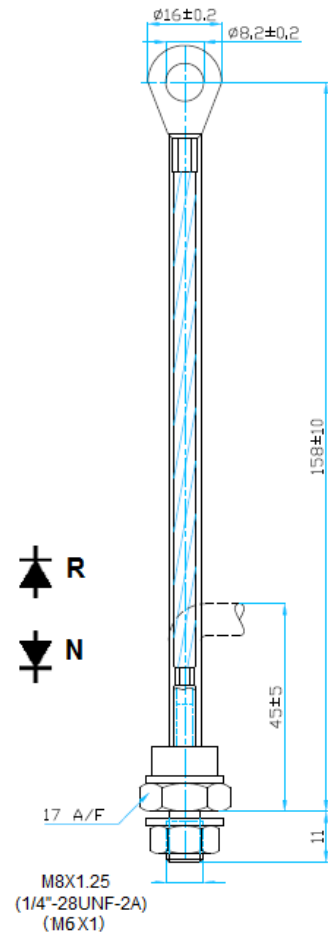
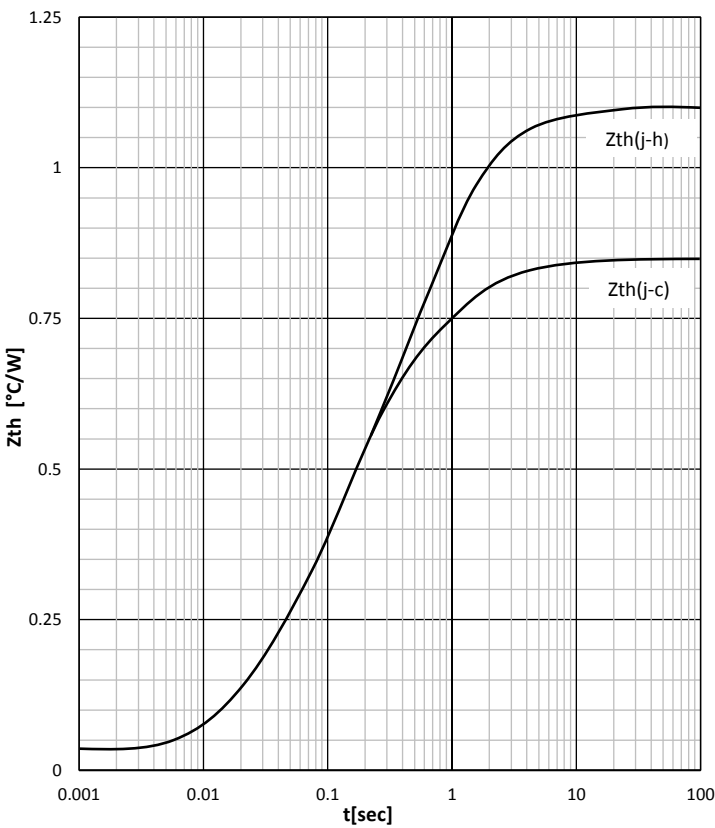

DISSIPATION CHARACTERISTICS

SQUARE WAVE


FORWARD CURRENT DERATING CURVE

SQUARE WAVE



FORWARD CHARACTERISTIC

SURGE CHARACTERISTICS

TRANSIENT THERMAL IMPEDANCE


Scomes srl reserves the right to change any specification without notice

issue:jul-2019